


	<h2>SI3475DV-T1-GE3</h2>
	<p>Hersteller-Teilenummer: SI3475DV-T1-GE3</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET P-CH 200V 0.95A 6-TSOP</p> <p>Datenblätter:  SI3475DV-T1-GE3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 51672 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SI3475DV-T1-GE3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET P-CH 200V 0.95A 6-TSOP
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	51672 pcs Stock
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	SOT-23-6 Thin, TSOT-23-6
Supplier Device-Gehäuse	6-TSOP
Verlustleistung (max)	2W (Ta), 3.2W (Tc)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	200V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	950mA (Tc)
Rds On (Max) @ Id, Vgs	1.61 Ohm @ 900mA, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	18nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	500pF @ 50V
Verpackung	Original-Reel®



















































SI3475DV-T1-GE3 ist neu im Original, Suche SI3475DV-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI3475DV-T1-GE3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI3475DV-T1-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI3477DV-T1-GE3 Vishay / Siliconix MOSFET P-CH 12V 8A 6-TSOP</p>	 <p>SI3474DV-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 100V 3.8A TSOP-6</p>	 <p>SI3476DV-T1-E3 VISHAY SI3476DV-T1-E3 VISHAY</p>	 <p>SI3476DV-T1-GE3 Vishay / Siliconix MOSFET N-CH 80V 4.6A TSOP-6</p>
 <p>SI3476DV-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 80V 4.6A TSOP-6</p>	 <p>SI3475DV-T1-E3 Electro-Films (EFI) / Vishay MOSFET P-CH 200V 0.95A 6-TSOP</p>	 <p>SI3475DV VISHAY VISHAY SOT-163</p>	 <p>SI3475DV-T1-E3 Vishay / Siliconix MOSFET P-CH 200V 0.95A 6-TSOP</p>

heiße Teile

Mehr

 SI3467DV	 SI3467DV-T1-E3	 SI3467DV-T1-E3	 SI3467DV-T1-GE3	 SI3467DV-T1-GE3
 SI3469DV-T1	 SI3469DV-T1-E3	 SI3469DV-T1-E3	 SI3469DV-T1-GE3	 SI3469DV-T1-GE3
 SI3471DV-T1-E3	 SI3473CDV-T1-E3	 SI3473CDV-T1-E3	 SI3473CDV-T1-GE3	 SI3473CDV-T1-GE3
 SI3473DDV-T1-GE3	 SI3473DV-T1-E3	 SI3473DV-T1-E3	 SI3473DV-T1-GE3	 SI3473DV-T1-GE3
 SI3474DV-T1-GE3	 SI3474DV-T1-GE3	 SI3475DV-T1-E3	 SI3475DV-T1-E3	 SI3475DV-T1-GE3
 SI3476DV-T1-E3	 SI3476DV-T1-GE3	 SI3476DV-T1-GE3	 SI3477DV-T1-E3	 SI3477DV-T1-GE3
 SI3477DV-T1-GE3	 SI3481DV-T1-E3	 SI3481DV-T1-E3	 SI3481DV-T1-GE3	 SI3481DV-T1-GE3
 SI3483CDV-T1-E3	 SI3483CDV-T1-E3	 SI3483CDV-T1-GE3	 SI3483CDV-T1-GE3	 SI3483DV-T1-E3
 SI3483DV-T1-E3	 SI3483DV-T1-GE3	 SI3483DV-T1-GE3	 SI3493BDV-T1-E3	 SI3493BDV-T1-E3
 SI3493BDV-T1-E3-S	 SI3493BDV-T1-GE3	 SI3493BDV-T1-GE3	 SI3493DDV-T1-GE3	 SI3493DDV-T1-GE3

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